









SN74AUP1G14

SCES578J-JUNE 2003-REVISED SEPTEMBER 2017

SN74AUP1G14 Low-Power Single Schmitt-Trigger Inverter

1 Features

- Latch-Up Performance Exceeds 100 mA Per JESD 78. Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Low Static-Power Consumption $(I_{CC} = 0.9 \ \mu A Maximum)$
- Low Dynamic-Power Consumption $(C_{pd} = 4.4 \text{ pF Typical at 3.3 V})$
- Low Input Capacitance ($C_1 = 1.5 \text{ pF Typical}$)
- Low Noise Overshoot and Undershoot <10% of V_{CC}
- Ioff Supports Partial-Power-Down Mode Operation
- **Includes Schmitt-Trigger Inputs**
- Wide Operating V_{CC} Range of 0.8 V to 3.6 V
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t_{pd} = 4.9 ns Maximum at 3.3 V

Applications 2

- **AV Receivers**
- Smartphones
- **Blu-ray Players and Home Theaters**
- **DVD Recorders and Players**
- Desktop or Notebook PCs
- Embedded PCs
- **GPS:** Personal Navigation Devices
- Mobile Internet Devices
- Portable Media Players
- Smoke Detectors
- Solid State Drive (SSD): Enterprise
- High-Definition (HDTV)
- Tablets: Enterprise
- Audio Docks: Portable
- DVR and DVS

3 Description

The AUP family is TI's premier solution to the industry's low power needs in battery-powered portable applications. This family assures a very low static and dynamic power consumption across the entire V_{CC} range of 0.8 V to 3.6 V, resulting in an increased battery life. This product also maintains excellent signal integrity (see AUP - The Lowest-Power Family and Excellent Signal Integrity).

This device functions as an independent gate with Schmitt-trigger inputs, which allows for slow input transition and better switching-noise immunity at the input.

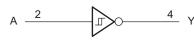
This device is fully specified for partial-power-down applications using Ioff. The Ioff circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

Device	Inform	ation ⁽¹⁾
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PACKAGE	BODY SIZE (NOM)						
SOT-23 (5)	2.90 mm x 1.60 mm						
SC70 (5)	2.00 mm x 1.25 mm						
SOT (5)	1.60 mm x 1.20 mm						
SON (6)	1.45 mm x 1.00 mm						
SON (6)	1.00 mm x 1.00 mm						
X2SON (5)	0.80 mm x 0.80 mm						
DSBGA (4)	0.76 mm x 0.76 mm						
	SOT-23 (5) SC70 (5) SOT (5) SON (6) SON (6) X2SON (5)						

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Logic Diagram (Positive Logic) (DBV, DCK, DRL, DRY, DSF, DPW, and YZP Packages)



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Logic Diagram (Positive Logic) (YFP Package)



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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision I (May 2010) to Revision J

Page

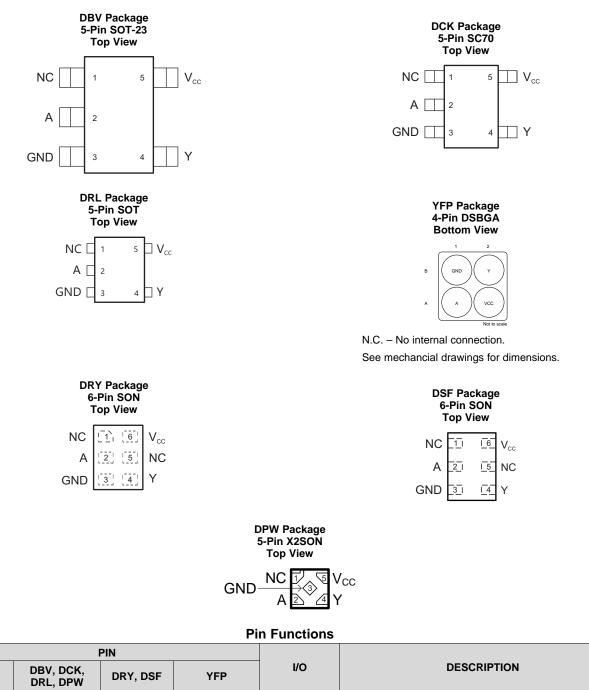
•	Added DPW (X2SON) package	. 1
•	Added Device Information table, Pin Configuration and Functions section, ESD Ratings table, Thermal Information table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and Mechanical, Packaging, and Orderable Information section.	. 1
•	Deleted Ordering Information table, see Mechanical, Packaging, and Orderable Information section at the end of the data sheet	. 1
•	Changed formatting of YFP package pinout drawing	. 3
•	Deleted YZP package from data sheet	. 3
•	Added Junction temperature, T _J in Absolute Maximum Ratings	. 4



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5 Pin Configuration and Functions



NAME	DBV, DCK, DRL, DPW	DRY, DSF	YFP	1/0	DESCRIPTION
A	2	2	A1	I	Logic Input
GND	3	3	B1	_	Ground
N.C.	1	1, 5	—	_	No internal connection
V _{CC}	5	6	A2	—	Positive Supply
Y	4	4	B2	0	Output

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6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		-0.5	4.6	V
VI	Input voltage ⁽²⁾		-0.5	4.6	V
Vo	Voltage range applied to any output in the high-	age range applied to any output in the high-impedance or power-off state ⁽²⁾		4.6	V
Vo	Voltage range applied to any output in the high	or low state ⁽²⁾	-0.5	V _{CC} + 0.5	V
I _{IK}	Input clamp current	V ₁ < 0		-50	mA
I _{OK}	Output clamp current	V _O < 0		-50	mA
I _O	Continuous output current			±20	mA
	Continuous current through V_{CC} or GND			±50	mA
TJ	Junction temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

6.2 ESD Ratings

			VALUE	UNIT
V	Electrostatio discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	2000	V
V(ESD)	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	1000	v

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

See⁽¹⁾

			MIN	МАХ	UNIT
V_{CC}	Supply voltage		0.8	3.6	V
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	V _{CC}	V
		V _{CC} = 0.8 V		-20	μA
I _{OH}		V _{CC} = 1.1 V		-1.1	
	High-level output current	$V_{CC} = 1.4 V$		-1.7	
		V _{CC} = 1.65 V		-1.9	mA
		V _{CC} = 2.3 V		-3.1	
		$V_{CC} = 3 V$		-4	
		$V_{CC} = 0.8 V$		20	μA
		V _{CC} = 1.1 V		1.1	
	Level and a dealer strength	V _{CC} = 1.4 V		1.7	
I _{OL}	Low-level output current	V _{CC} = 1.65 V		1.9	mA
		V _{CC} = 2.3 V		3.1	
		$V_{CC} = 3 V$		4	
T _A	Operating free-air temperature	· · · ·	-40	85	°C

 All unused inputs of the device must be held at V_{CC} or GND to assure proper device operation. See Implications of Slow or Floating CMOS Inputs.

6.4 Thermal Information

			SN74AUP1G14						
	THERMAL METRIC ⁽¹⁾	DRY (SON)	DSF (SON)	YFP (DSBGA)	DPW (X2SON)	DBV (SOT-23)	DCK (SC70)	DRL (SOT)	UNIT
			6 PINS	4 PINS	5 PINS	5 PINS	5 PINS	5 PINS	
R_{\thetaJA}	Junction-to-ambient thermal resistance	347.8	386.2	179.3	489.2	289.1	325.1	324.4	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	237.7	192.9	2.8	226.3	213.7	229.1	156.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	210.6	242.2	58.3	352.9	123.0	123.2	172.9	°C/W
ΨJT	Junction-to-top characterization parameter	64.4	28.9	1.1	38.2	104.5	96.3	21.6	°C/W
ΨJB	Junction-to-board characterization parameter	210.6	241.9	58.6	352.1	122.3	122.4	173.6	°C/W
R _{0JC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	150.8	N/A	N/A	N/A	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN TYP	MAX	UNIT
		T _A = 25°C	0.8 V	0.3	0.6	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	0.0 V	0.3	0.0	
		$T_A = 25^{\circ}C$	1.1 V	0.53	0.9	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	1.1 V	0.55	0.9	
		$T_A = 25^{\circ}C$	1.4 V	0.74	1.11	
V _{T+}	Positive-going input	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	1.4 V	0.74	1.11	V
vT+	threshold voltage	$T_A = 25^{\circ}C$	1.65 V	0.91	1.29	v
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	1.03 V	0.91	1.29	
		$T_A = 25^{\circ}C$	2.3 V	1.37	1.77	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	2.5 V	1.57	1.77	
		$T_A = 25^{\circ}C$	3 V	1.88	2.29	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	5 V	1.00	2.23	
		$T_A = 25^{\circ}C$	0.8 V	0.1	0.6	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	0.0 V	0.1	0.0	
		$T_A = 25^{\circ}C$	1.1 V	0.26	0.65	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	1.1 V	0.20	0.05	
		$T_A = 25^{\circ}C$	1.4 V	0.39	0.75	
V _{T-}	Negative-going input	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	1.4 V	0.39	0.75	V
v _{T-}	threshold voltage	$T_A = 25^{\circ}C$	1.65 V	0.47	0.84	v
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	1.05 V	0.47	0.04	
		$T_A = 25^{\circ}C$	2.3 V	0.60	1.04	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	2.3 V	0.69	1.04	
		$T_A = 25^{\circ}C$	2.)/	0.00	1.04	
		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	3 V	0.88	1.24	

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Electrical Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER	TES	T CONDITIONS	V _{cc}	MIN	TYP MAX	UNIT
	T _A = 25°C		0.8 V	0.07	0.5	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$					
	T _A = 25°C				0.46	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
	T _A = 25°C		1.4 V	0.18	0.56	
$\Delta V_{T} \qquad \begin{array}{c} \text{Hysteresis} \\ (V_{T+} - V_{T-}) \end{array}$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$					V
$(V_{T+} - V_{T-})$	T _A = 25°C		1.65 V	0.27	0.66	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$					
	T _A = 25°C		2.3 V	0.53	0.92	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				0.27 0.66 0.53 0.92 0.79 1.31 0.1 V _{CC} .11 .03 .32 1.3 .05 .97 1.9 .85 .72 2.6 2.55 0.1 0.3 × V _{CC}	
	$T_A = 25^{\circ}C$		3 V	0.79	1.31	
	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	T 0500				
	I _{OH} = -20 μA	$T_A = 25^{\circ}C$	0.8 V to 3.6 V	V _{CC} - 0.1		
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
	I _{OH} = -1.1 mA	$T_A = 25^{\circ}C$	1.1 V	0.75 × V _{CC}		
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		0.7 × V _{CC}		
	$I_{OH} = -1.7 \text{ mA}$	$T_{A} = 25^{\circ}C$	1.4 V			
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
V _{OH}	$I_{OH} = -1.9 \text{ mA}$ $I_{OH} = -2.3 \text{ mA}$	$T_{A} = 25^{\circ}C$	1.65 V			
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				V
		$T_{A} = 25^{\circ}C$				
		$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$ $T_{A} = 25^{\circ}C$	2.3 V			
	I _{OH} = -3.1 mA	$T_A = 25 \text{ C}$ $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$				
	$I_{OH} = -2.7 \text{ mA}$ $I_{OH} = -4 \text{ mA}$	$T_A = -40^{\circ} \text{C} + 60^{\circ} \text{C}$ $T_A = 25^{\circ} \text{C}$				
		$T_A = 23 \text{ C}$ $T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$				
		$T_A = -40^{\circ} \text{C} + 60^{\circ} \text{C}$ $T_A = 25^{\circ} \text{C}$	3 V			
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
		$T_A = 25^{\circ}C$		2.00		
	I _{OL} = 20 μA	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$	0.8 V to 3.6 V		0.1	
		$T_A = 25^{\circ}C$			0.2	
	I _{OL} = 1.1 mA	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$	1.1 V			
		$T_A = 25^{\circ}C$				
	I _{OL} = 1.7 mA	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$	1.4 V			
		$T_A = 25^{\circ}C$				
	I _{OL} = 1.9 mA	$T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C$	1.65 V			
V _{OL}		$T_A = 25^{\circ}C$				V
	I _{OL} = 2.3 mA	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$				
		T _A = 25°C	2.3 V		0.44	
	I _{OL} = 3.1 mA	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			0.45	
		T _A = 25°C			0.31	
	I _{OL} = 2.7 mA	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			0.33	
		T _A = 25°C	3 V		0.44	
	$I_{OL} = 4 \text{ mA}$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$			0.45	
		T _A = 25°C	0.111		0.1	
I _I A input	$V_1 = GND$ to 3.6 V	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0 V to 3.6 V		0.5	μΑ
	V _I or	$T_A = 25^{\circ}C$			0.2	
I _{OFF}	$V_0 = 0 V \text{ to } 3.6 V$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0 V		1.31 1.33 1.34 1.35 1.31 1.33 1.33 1.33 1.33 1.33 1.34 1.35 1.31 1.33 1.33 1.33 1.33 1.34 1.35 1.31 1.33 1.35 1.31 1.33 1.33 1.33 1.35 1.31 1.33 1.33 1.33 1.35 1.31 1.33 1.33 1.35 1.31 1.35 1.31 1.33 1.35 1	μA
	V ₁ or	T _A = 25°C	0.1/1 0.0.1/		0.2	
ΔI _{OFF}	$V_0 = 0 V \text{ to } 3.6 V$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0 V to 0.2 V		0.6	

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Electrical Characteristics (continued)

PARAMETER	TEST CO	ONDITIONS	V _{cc}	MIN	TYP MAX	UNIT	
1	$V_1 = GND \text{ or } (V_{CC} \text{ to } 3.6 \text{ V})$	$T_A = 25^{\circ}C$	- 0.8 V to 3.6 V		0.5		
Icc	$I_0 = 0$	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	0.8 V 10 3.8 V		0.9	μA	
	$V_{I} = V_{CC} - 0.6 V$	T _A = 25°C	- 3.3 V		40		
ΔI_{CC}	$V_{I} = V_{CC} - 0.6 V$ $I_{O} = 0$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	3.3 V		50	μA	
C C		$T_A = -40^{\circ}C$ to $+85^{\circ}C$	0 V	4 5		~ F	
C ₁	$V_{I} = V_{CC}$ or GND	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	3.6 V	1.5		pF	
Co	V _O = GND	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	0 V	2.5		pF	

over operating free-air temperature range (unless otherwise noted)

6.6 Switching Characteristics: $C_L = 5 \text{ pF}$

over recommended operating free-air temperature range, $C_L = 5 \text{ pF}$ (unless otherwise noted) (see Figure 2 and Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST C	CONDITIONS	MIN	ТҮР	МАХ	UNIT
			$V_{CC} = 0.8 V$	$T_A = 25^{\circ}C$		16.3		
		V _{CC} = 1.2 V ± 0.1 V	$T_A = 25^{\circ}C$	4.2	6.9	11.7		
		$v_{CC} = 1.2 v \pm 0.1 v$	$T_A = -40^{\circ}C$ to +85°C	0.9		15		
		$V_{CC} = 1.5 V \pm 0.1 V$	$T_A = 25^{\circ}C$	3.7	5.2	8.4		
			$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	1.7		10.7		
t _{pd}	А	Y	$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	$T_A = 25^{\circ}C$	3.3	4.4	6.9	ns
				$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	1.9		8.5	
				T _A = 25°C	2.8	3.5	4.8	
		$V_{CC} = 2.5 V \pm 0.2 V$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	1.8		6.1		
				T _A = 25°C	2.5	3	4	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	1.7		4.9	

6.7 Switching Characteristics: $C_L = 10 \text{ pF}$

over recommended operating free-air temperature range, $C_L = 10 \text{ pF}$ (unless otherwise noted) (see Figure 2 and Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST (CONDITIONS	MIN	ТҮР	МАХ	UNIT
			V _{CC} = 0.8 V	$T_A = 25^{\circ}C$		18.4		
			V 12V 01V	$T_A = 25^{\circ}C$	4.6	7.9	13.4	
			$V_{CC} = 1.2 V \pm 0.1 V$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	1.3		16.7	
		Y	$V_{CC} = 1.5 V \pm 0.1 V$	$T_A = 25^{\circ}C$	4	6	9.6	
				$T_A = -40^{\circ}C$ to +85°C	2.2		11.8	
t _{pd}	А		V _{CC} = 1.8 V ± 0.15 V	$T_A = 25^{\circ}C$	3.6	5	7.9	ns
				$T_A = -40^{\circ}C$ to +85°C	2.4		9.5	
			V 05V 00V	$T_A = 25^{\circ}C$	3.2	4	5.5	
			$V_{CC} = 2.5 V \pm 0.2 V$	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	2.3		6.8	
				T _A = 25°C	2.9	3.5	4.6	
			$V_{CC} = 3.3 V \pm 0.3 V$	$T_A = -40^{\circ}C$ to +85°C	2.1		5.6	

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6.8 Switching Characteristics: C_L = 15 pF

over recommended operating free-air temperature range, $C_L = 15 \text{ pF}$ (unless otherwise noted) (see Figure 2 and Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST C	CONDITIONS	MIN	ТҮР	МАХ	UNIT
			$V_{CC} = 0.8 V$	$T_A = 25^{\circ}C$		20.1		
			V _{CC} = 1.2 V ± 0.1 V	$T_A = 25^{\circ}C$	5.5	8.7	14	
			$v_{\rm CC} = 1.2 \ v \pm 0.1 \ v$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	2.5		17.3	
			$V_{CC} = 1.5 V \pm 0.1 V$	$T_A = 25^{\circ}C$	4.7	6.7	10	
		Y		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	3		12.5	
t _{pd}	А		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	$T_A = 25^{\circ}C$	4.2	5.6	8.3	ns
				$T_A = -40^{\circ}C$ to $+85^{\circ}C$	3		10.1	
			$V_{CC} = 2.5 V \pm 0.2 V$	$T_A = 25^{\circ}C$	3.6	4.5	5.9	
				$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	2.7		7.4	
				$T_A = 25^{\circ}C$	3.3	3.9	5	
			$V_{CC} = 3.3 V \pm 0.3 V$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	2.5		6.1	

6.9 Switching Characteristics: C_L = 30 pF

over recommended operating free-air temperature range, $C_L = 30 \text{ pF}$ (unless otherwise noted) (see Figure 2 and Figure 3)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST C	CONDITIONS	MIN	ТҮР	МАХ	UNIT
			$V_{CC} = 0.8 V$	$T_A = 25^{\circ}C$		25.7		
			V _{CC} = 1.2 V ± 0.1 V	$T_A = 25^{\circ}C$	7.4	11.2	17.1	
		$v_{CC} = 1.2 v \pm 0.1 v$	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	4.5		20.5		
			$T_A = 25^{\circ}C$	6.1	8.5	12.3		
		Y	$V_{CC} = 1.5 V \pm 0.1 V$	$T_A = -40^{\circ}C$ to $+85^{\circ}C$	4.6		14.7	
t _{pd}	А		$V_{CC} = 1.8 \text{ V} \pm 0.15 \text{ V}$	$T_A = 25^{\circ}C$	5.4	7.2	10.3	ns
				$T_A = -40^{\circ}C$ to +85°C	4.1		12	
				$T_A = 25^{\circ}C$	4.7	5.7	7.4	
			$V_{CC} = 2.5 V \pm 0.2 V$	$T_A = -40^{\circ}C$ to +85°C	3.7		8.8	
				T _A = 25°C	4.2	5	6.2	
			$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	3.5		7.3	

6.10 Operating Characteristics

 $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V _{cc}	TYP	UNIT
			0.8 V	4	
		1.2 V ± 0.1 V	4		
6		f = 10 MHz	1.5 V ± 0.1 V	4.1	- pF
C _{pd}	Power dissipation capacitance	I = TO MHZ	1.8 V ± 0.15 V	4.1	
			2.5 V ± 0.2 V	4.3	
			3.3 V ± 0.3 V	4.4	

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6.11 Typical Characteristics

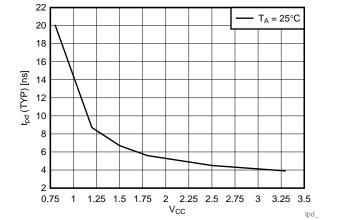


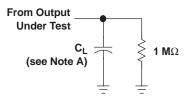
Figure 1. Typical Propagation Delay vs. Supply Voltage (C_L = 15 pF

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XAS

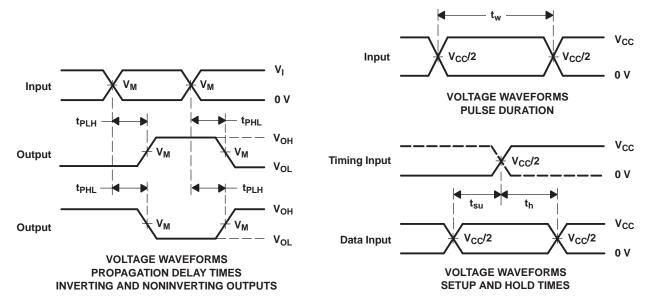
7 Parameter Measurement Information

7.1 (Propagation Delays, Setup and Hold Times, and Pulse Width)



	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V_{CC} = 2.5 V \pm 0.2 V	V _{CC} = 3.3 V ± 0.3 V
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
VM	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
VI	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}

LOAD CIRCUIT



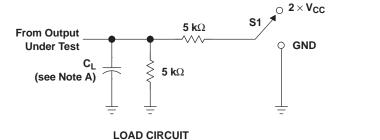
NOTES: A. CL includes probe and jig capacitance.

- B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 Ω , t_f/t_f = 3 ns.
- C. The outputs are measured one at a time, with one transition per measurement.
- D. t_{PLH} and t_{PHL} are the same as t_{pd} . E. All parameters and waveforms are not applicable to all devices.

Figure 2. Load Circuit And Voltage Waveforms

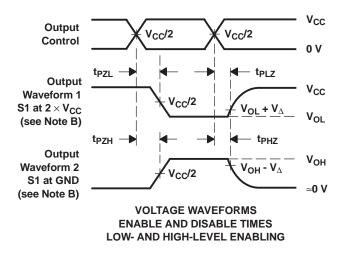


7.2 (Enable and Disable Times)



TEST	S1
t _{PLZ} /t _{PZL}	$2 \times V_{CC}$
t _{PHZ} /t _{PZH}	GND

	V _{CC} = 0.8 V	V _{CC} = 1.2 V ± 0.1 V	V _{CC} = 1.5 V ± 0.1 V	V _{CC} = 1.8 V ± 0.15 V	V _{CC} = 2.5 V ± 0.2 V	$V_{CC} = 3.3 \text{ V}$ $\pm 0.3 \text{ V}$
С _L	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V _M	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2	V _{CC} /2
V _I	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}	V _{CC}
V _Δ	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_O = 50 $\Omega,$ tr/tf = 3 ns.
 - D. The outputs are measured one at a time, with one transition per measurement.
 - E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
 - F. t_{PZL} and t_{PZH} are the same as t_{en}.
 - G. All parameters and waveforms are not applicable to all devices.

Figure 3. Load Circuit And Voltage Waveforms



8 Detailed Description

8.1 Overview

This device functions as an independent gate with Schmitt-trigger inputs, which allows for slow input transition and better switching-noise immunity at the input.

This device is fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs when the device is powered down. This inhibits current backflow into the device which prevents damage to the device.

8.2 Functional Block Diagrams



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Figure 4. Logic Diagram (Positive Logic) (DBV, DCK, DRL, DRY, DSF, DPW, and YZP Packages)

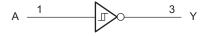




Figure 5. Logic Diagram (Positive Logic) (YFP Package)

8.3 Feature Description

8.3.1 Balanced CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The drive capability of this device creates fast edges into light loads so routing and load conditions should be considered to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. It is important for the power output of the device to be limited to avoid thermal runaway and damage due to over-current. The electrical and thermal limits defined the in the *Absolute Maximum Ratings* table must be followed at all times.

8.3.2 Schmitt-Trigger Inputs

Standard CMOS inputs are high impedance and are typically modeled as a resistor in parallel with the input capacitance given in the *Electrical Characteristics* table. The worst case resistance is calculated with the maximum input voltage, given in the *Absolute Maximum Ratings* table, and the maximum input leakage current, given in the *Electrical Characteristics* table, using ohm's law ($R = V \div I$).

The Schmitt-trigger input architecture provides hysteresis as defined by ΔV_T in the *Electrical Characteristics* table, which makes this device extremely tolerant to slow or noisy inputs. While the inputs can be driven much slower than standard CMOS inputs, it is still recommended to properly terminate unused inputs. Driving the inputs slowly will also increase dynamic current consumption of the device. For additional information regarding Schmitt-trigger inputs, see *Understanding Schmitt Triggers*.



Feature Description (continued)

8.3.3 Clamp Diodes

The inputs and outputs to this device have negative clamping diodes.

CAUTION

Voltages beyond the values specified in the *Absolute Maximum Ratings* table can cause damage to the device. The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

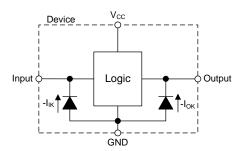


Figure 6. Electrical Placement of Clamping Diodes for Each Input and Output

8.3.4 Partial Power Down (I_{off})

The inputs and outputs for this device enter a high impedance state when the supply voltage is 0 V. The maximum leakage into or out of any input or output pin on the device is specified by I_{off} in the *Electrical Characteristics* table.

8.3.5 Over-Voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage so long as they remain below the maximum input voltage value specified in the *Absolute Maximum Ratings* table.

8.4 Device Functional Modes

Table 1 lists the functional modes of the SN74AUP1G14.

INPUT A	OUTPUT Y
Н	L
L	Н

Table 1. Function Table

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9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

Mechanical input elements, such as push buttons or rotary knobs, offer simple ways to interact with electronic systems. Typically, these elements have recoil or bouncing, where the mechanical element makes and breaks contact multiple times during human interaction. This bouncing can cause one or more repeated signals to be passed, triggering multiple actions when only a single input was intended. One potential solution to mitigating these multiple inputs is by utilizing a Schmitt-trigger to create a debounce circuit. Figure 7 shows an example of this solution.

9.2 Typical Application

The input due to the push button switches multiple times, causing the output of a non Schmitt-trigger device to trigger multiple times, while the Schmitt-trigger input device with RC delay limits the output pulse to a single pulse desired by the user. The separated positive and negative input voltage threshold values prevent multiple triggers from occurring, see the *Electrical Characteristics* table for V_{T+} , V_{T-} , and V_{hys} values.

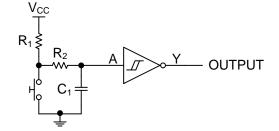


Figure 7. Push Button Debounce Circuit Schematic

9.2.1 Design Requirements

This device uses CMOS technology and has balanced output drive. Take care to avoid bus contention because it can drive currents that would exceed maximum limits. The drive strength also creates fast edges into light loads so routing and load conditions should be considered to prevent ringing.

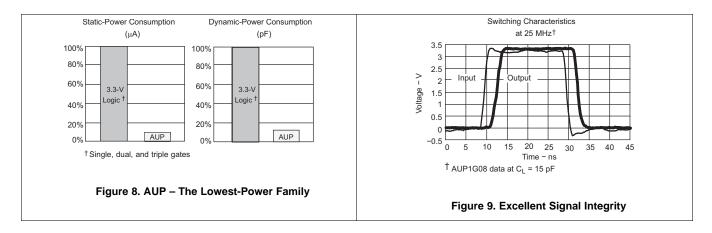
9.2.2 Detailed Design Procedure

- 1. Recommended Input Conditions:
 - For specified high and low levels, see (V_{T+} and V_{T-}) in the *Electrical Characteristics* table.
 - Inputs are overvoltage tolerant allowing them to go as high as (V₁ max) in the *Recommended Operating Conditions* table at any valid V_{CC}.
- 2. Recommended Output Conditions:
 - Load currents should not exceed (I_O max) per output and should not exceed (Continuous current through V_{CC} or GND) total current for the part. These limits are located in the *Absolute Maximum Ratings* table.



Typical Application (continued)

9.2.3 Application Curves





10 Power Supply Recommendations

The power supply can be any voltage between the min and max supply voltage rating located in the *Recommended Operating Conditions* table.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. It is ok to parallel multiple bypass caps to reject different frequencies of noise. 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

Even low data rate digital signals can contain high-frequency signal components due to fast edge rates. When a printed-circuit board (PCB) trace turns a corner at a 90° angle, a reflection can occur. A reflection occurs primarily because of the change of width of the trace. At the apex of the turn, the trace width increases to 1.414 times the width. This increase upsets the transmission-line characteristics, especially the distributed capacitance and self–inductance of the trace which results in the reflection. Not all PCB traces can be straight and therefore some traces must turn corners. Figure 10 shows progressively better techniques of rounding corners. Only the last example (BEST) maintains constant trace width and minimizes reflections.

An example layout is given in Figure 11 for the DPW (X2SON-5) package. This example layout includes a 0402 (metric) capacitor and uses the measurements found in the example board layout appended to this end of this datasheet. A via of diameter 0.1 mm (3.973 mil) is placed directly in the center of the device. This via can be used to trace out the center pin connection through another board layer, or it can be left out of the layout

11.2 Layout Example

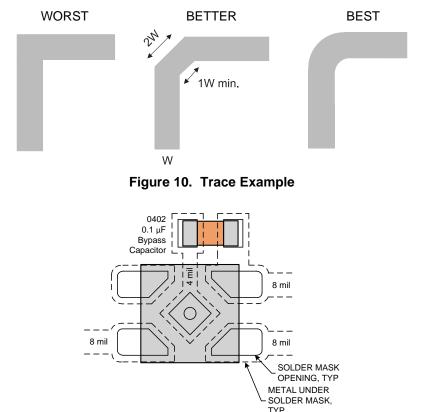


Figure 11. Example Layout With DPW (X2SON-5) Package



12 Device and Documentation Support

12.1 Documentation Support

12.1.1 Related Documentation

For related documentation see the following: Implications of Slow or Floating CMOS Inputs

12.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.4 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.6 Glossary

SLYZ022 — TI Glossary.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



23-Jan-2018

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74AUP1G14DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H14R	Samples
SN74AUP1G14DBVRG4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H14R	Samples
SN74AUP1G14DBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	H14R	Samples
SN74AUP1G14DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFF, HFK, HF R)	Samples
SN74AUP1G14DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFF, HFK, HF R)	Samples
SN74AUP1G14DCKRG4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFF, HFK, HF R)	Samples
SN74AUP1G14DCKT	ACTIVE	SC70	DCK	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF5, HFK, HFR)	Samples
SN74AUP1G14DPWR	ACTIVE	X2SON	DPW	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	BZ	Samples
SN74AUP1G14DRLR	ACTIVE	SOT-5X3	DRL	5	4000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	(HF7, HFR)	Samples
SN74AUP1G14DRYR	ACTIVE	SON	DRY	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	HF	Samples
SN74AUP1G14DSFR	ACTIVE	SON	DSF	6	5000	Green (RoHS & no Sb/Br)	CU NIPDAU CU NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	HF	Samples
SN74AUP1G14YFPR	ACTIVE	DSBGA	YFP	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM		HF N	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.



PACKAGE OPTION ADDENDUM

23-Jan-2018

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



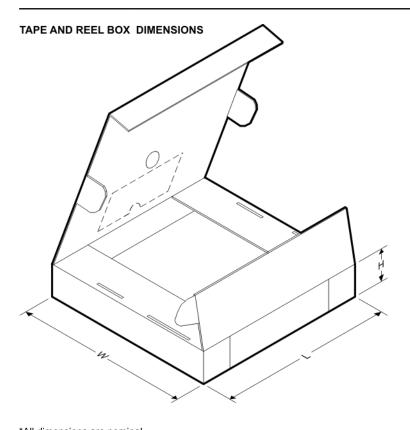
*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1G14DBVR	SOT-23	DBV	5	3000	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G14DBVT	SOT-23	DBV	5	250	180.0	8.4	3.23	3.17	1.37	4.0	8.0	Q3
SN74AUP1G14DCKR	SC70	DCK	5	3000	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
SN74AUP1G14DCKR	SC70	DCK	5	3000	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G14DCKR	SC70	DCK	5	3000	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74AUP1G14DCKT	SC70	DCK	5	250	178.0	9.2	2.4	2.4	1.22	4.0	8.0	Q3
SN74AUP1G14DCKT	SC70	DCK	5	250	180.0	9.2	2.3	2.55	1.2	4.0	8.0	Q3
SN74AUP1G14DPWR	X2SON	DPW	5	3000	178.0	8.4	0.91	0.91	0.5	2.0	8.0	Q3
SN74AUP1G14DRLR	SOT-5X3	DRL	5	4000	180.0	8.4	1.98	1.78	0.69	4.0	8.0	Q3
SN74AUP1G14DRYR	SON	DRY	6	5000	180.0	9.5	1.15	1.6	0.75	4.0	8.0	Q1
SN74AUP1G14DSFR	SON	DSF	6	5000	180.0	9.5	1.16	1.16	0.5	4.0	8.0	Q2
SN74AUP1G14YFPR	DSBGA	YFP	4	3000	178.0	9.2	0.89	0.89	0.58	4.0	8.0	Q1

TEXAS INSTRUMENTS

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PACKAGE MATERIALS INFORMATION

5-Nov-2017



*All dimensions are nominal							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP1G14DBVR	SOT-23	DBV	5	3000	202.0	201.0	28.0
SN74AUP1G14DBVT	SOT-23	DBV	5	250	202.0	201.0	28.0
SN74AUP1G14DCKR	SC70	DCK	5	3000	202.0	201.0	28.0
SN74AUP1G14DCKR	SC70	DCK	5	3000	180.0	180.0	18.0
SN74AUP1G14DCKR	SC70	DCK	5	3000	205.0	200.0	33.0
SN74AUP1G14DCKT	SC70	DCK	5	250	180.0	180.0	18.0
SN74AUP1G14DCKT	SC70	DCK	5	250	205.0	200.0	33.0
SN74AUP1G14DPWR	X2SON	DPW	5	3000	205.0	200.0	33.0
SN74AUP1G14DRLR	SOT-5X3	DRL	5	4000	202.0	201.0	28.0
SN74AUP1G14DRYR	SON	DRY	6	5000	184.0	184.0	19.0
SN74AUP1G14DSFR	SON	DSF	6	5000	184.0	184.0	19.0
SN74AUP1G14YFPR	DSBGA	YFP	4	3000	220.0	220.0	35.0

DCK (R-PDSO-G5)

PLASTIC SMALL-OUTLINE PACKAGE



- NOTES: A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
 - D. Falls within JEDEC MO-203 variation AA.



LAND PATTERN DATA



NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



GENERIC PACKAGE VIEW

USON - 0.6 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4207181/G

DRY0006A



PACKAGE OUTLINE

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.



DRY0006A

EXAMPLE BOARD LAYOUT

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

3. For more information, see QFN/SON PCB application report in literature No. SLUA271 (www.ti.com/lit/slua271).



DRY0006A

EXAMPLE STENCIL DESIGN

USON - 0.6 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



GENERIC PACKAGE VIEW

X2SON - 0.4 mm max height PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



4211218-3/D

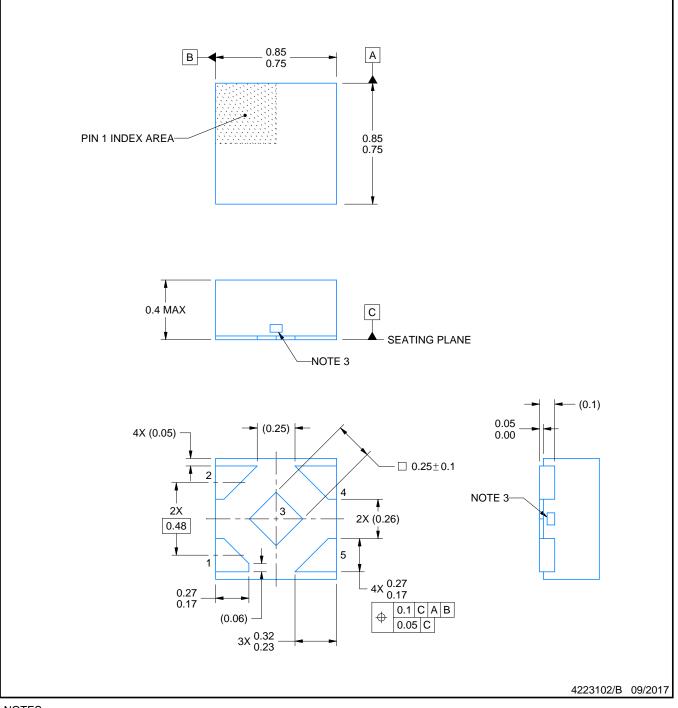
DPW0005A



PACKAGE OUTLINE

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.2. This drawing is subject to change without notice.
- 3. The size and shape of this feature may vary.

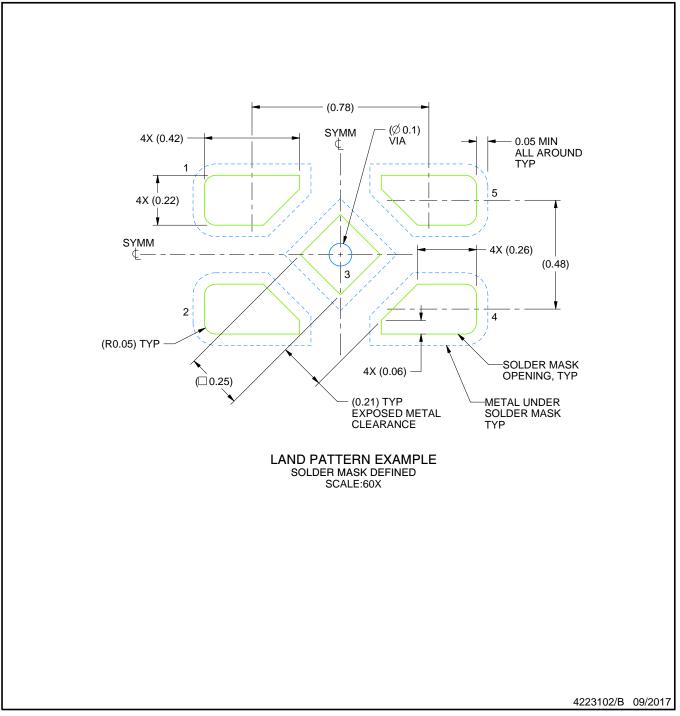


DPW0005A

EXAMPLE BOARD LAYOUT

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, refer to QFN/SON PCB application note in literature No. SLUA271 (www.ti.com/lit/slua271).

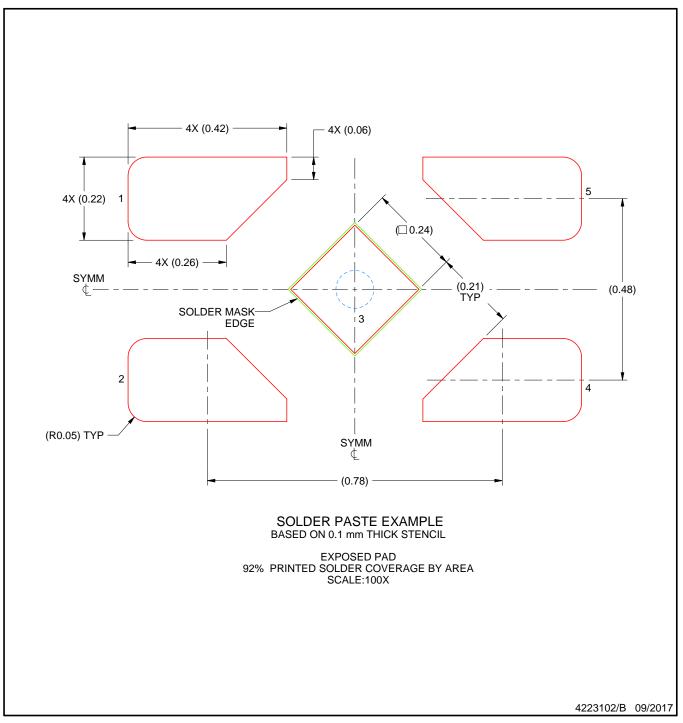


DPW0005A

EXAMPLE STENCIL DESIGN

X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



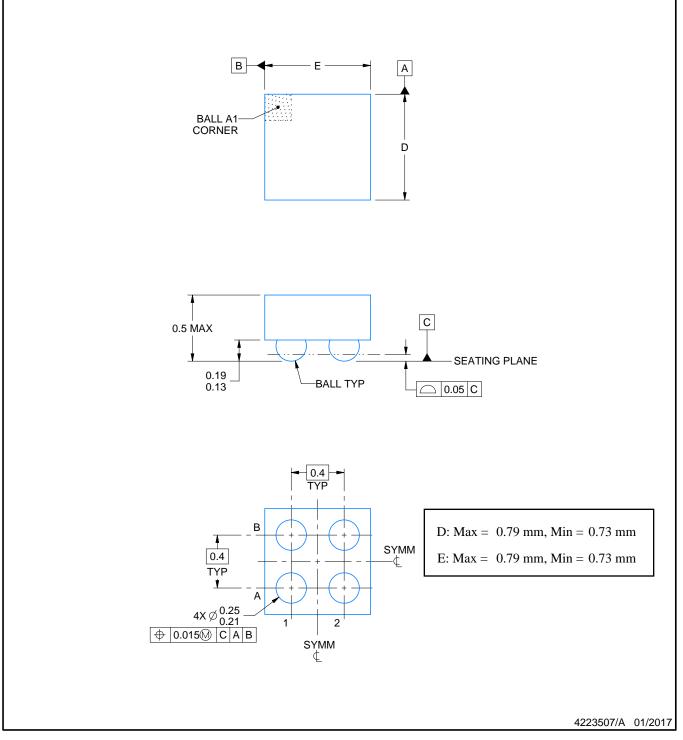
YFP0004



PACKAGE OUTLINE

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

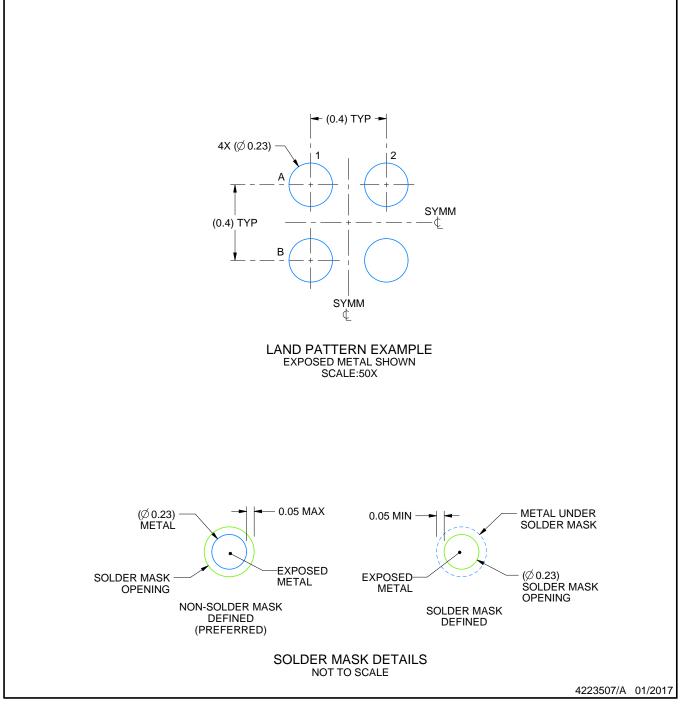


YFP0004

EXAMPLE BOARD LAYOUT

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).

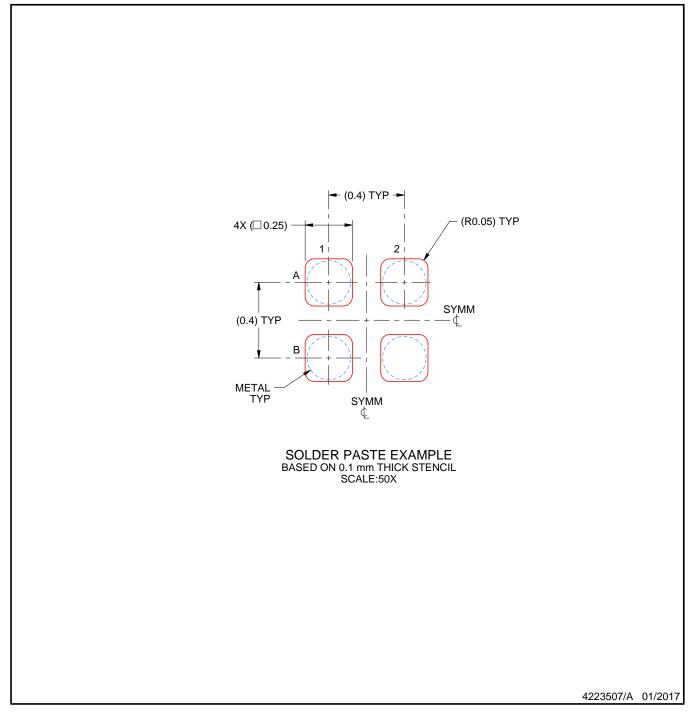


YFP0004

EXAMPLE STENCIL DESIGN

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



DBV 5

GENERIC PACKAGE VIEW

SOT-23 - 1.45 mm max height SMALL OUTLINE TRANSISTOR



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.



EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Board assembly site may have different recommendations for stencil design.



^{6.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



PACKAGE OUTLINE

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC MO-178.



EXAMPLE BOARD LAYOUT

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.

5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



EXAMPLE STENCIL DESIGN

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Board assembly site may have different recommendations for stencil design.



^{6.} Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES:

All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994. Α. B. This drawing is subject to change without notice.

🖄 Body dimensions do not include mold flash, interlead flash, protrusions, or gate burrs. Mold flash, interlead flash, protrusions, or gate burrs shall not exceed 0,15 per end or side.





DRL (R-PDSO-N5)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.
- E. Maximum stencil thickness 0,127 mm (5 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Side aperture dimensions over-print land for acceptable area ratio > 0.66. Customer may reduce side aperture dimensions if stencil manufacturing process allows for sufficient release at smaller opening.



MECHANICAL DATA

PLASTIC SMALL OUTLINE NO-LEAD



NOTES:

DSF (S-PX2SON-N6)

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing Per ASME Y14.5M.
 This drawing is subject to change without notice.
 Reference JEDEC registration MO-287, variation X2AAF.





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads. If 2 mil solder mask is outside PCB vendor capability, it is advised to omit solder mask.
- E. Maximum stencil thickness 0,1016 mm (4 mils). All linear dimensions are in millimeters.
- F. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- G. Suggest stencils cut with lasers such as Fiber Laser that produce the greatest positional accuracy.
- H. Component placement force should be minimized to prevent excessive paste block deformation.



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